

RELIABILITY REPORT  
FOR  
MAX14946EWE+T  
PLASTIC ENCAPSULATED DEVICES

October 12, 2016

**MAXIM INTEGRATED**

160 RIO ROBLES  
SAN JOSE, CA 95134

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Quality Assurance
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## Conclusion

The MAX14946EWE+T successfully meets the quality and reliability standards required of all Maxim Integrated products. In addition, Maxim Integrated's continuous reliability monitoring program ensures that all outgoing product will continue to meet Maxim Integrated's quality and reliability standards.

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### I. Device Description

#### A. General

The MAX14946 isolated RS-485/RS-422 transceiver provides 2750V<sub>RMS</sub> (60s) of galvanic isolation between the cable side (RS-485/RS-422 driver/receiver side) and the UART side of the device. Isolation improves communication by breaking ground loops and reduces noise when there are large differences in ground potential between ports. Signals are passed across the isolation barrier through integrated high-voltage capacitors. This device allows for robust communication at any speed up to 500kbps. The device includes an integrated 450kHz transformer driver for power transfer to the cable side of the transceiver using an external transformer. An integrated LDO provides a simple and space-efficient architecture for providing power to the cable-side of the IC. The device includes one half-duplex driver/receiver channel. The receiver is 1/8-unit load, allowing up to 256 transceivers on a common bus. Integrated true fail-safe circuitry ensures a logic-high on the receiver output when inputs are shorted or open. Undervoltage lockout disables the driver when cable-side or UART-side power supplies are below functional levels. The driver outputs/receiver inputs are protected from ±30kV electrostatic discharge (ESD) to GNDB on the cable side, as specified by the Human Body Model (HBM). The MAX14946 is available in a wide-body, 16-pin SOIC package and operates over the -40°C to +85°C temperature range.

## II. Manufacturing Information

A. Description/Function:	2.75kV <sub>RMS</sub> Isolated 500kbps Half-Duplex RS-485/RS-422 Transceiver with ±30kV ESD Protection and Integrated Transformer Driver
B. Process:	S18
C. Fabrication Location:	USA
D. Assembly Location:	Taiwan
E. Date of Initial Production:	December 18, 2015

## III. Packaging Information

A. Package Type:	16-pin SOIC Hybrid
B. Lead Frame:	Copper
C. Lead Finish:	100% matte Tin
D. Die Attach:	Conductive
E. Bondwire:	Au (1 mil dia.)
F. Mold Material:	Epoxy with silica filler
G. Assembly Diagram:	#31-4925
H. Flammability Rating:	Class UL94-V0
I. Classification of Moisture Sensitivity per JEDEC standard J-STD-020-C	Level 1
J. Single Layer Theta Ja:	N/A°C/W
K. Single Layer Theta Jc:	N/A°C/W
L. Multi Layer Theta Ja:	71°C/W
M. Multi Layer Theta Jc:	23°C/W

## IV. Die Information

A. Passivation:	Si <sub>3</sub> N <sub>4</sub> /SiO <sub>2</sub> (Silicon nitride/ Silicon dioxide)
B. Interconnect:	Al/0.5%Cu with Ti/TiN Barrier
C. Backside Metallization:	None
D. Minimum Metal Width:	0.23 microns (as drawn)
E. Minimum Metal Spacing:	0.23 microns (as drawn)
F. Bondpad Dimensions:	
G. Isolation Dielectric:	SiO <sub>2</sub>
H. Die Separation Method:	Wafer Saw

## V. Quality Assurance Information

- A. Quality Assurance Contacts: Eric Wright (Reliability Engineering)  
Bryan Preeshl (Vice President of QA)
- B. Outgoing Inspection Level: 0.1% for all electrical parameters guaranteed by the Datasheet.  
0.1% for all Visual Defects.
- C. Observed Outgoing Defect Rate: < 50 ppm
- D. Sampling Plan: Mil-Std-105D

## VI. Reliability Evaluation

### A. Accelerated Life Test

The results of the 135C biased (static) life test are shown in Table 1. Using these results, the Failure Rate ( $\lambda$ ) is calculated as follows:

$$\lambda = \frac{1}{\text{MTTF}} = \frac{1.83}{192 \times 4340 \times 80 \times 2} \quad (\text{Chi square value for MTTF upper limit})$$

(where 4340 = Temperature Acceleration factor assuming an activation energy of 0.8eV)

$$\lambda = 13.7 \times 10^{-9}$$

$$\lambda = 13.7 \text{ F.I.T. (60\% confidence level @ 25°C)}$$

The following failure rate represents data collected from Maxim Integrated's reliability monitor program. Maxim Integrated performs quarterly life test monitors on its processes. This data is published in the Reliability Report found at <http://www.maximintegrated.com/qa/reliability/monitor>. Cumulative monitor data for the S18 Process results in a FIT Rate of 0.06@ 25C and 0.93 @ 55C (0.8 eV, 60% UCL)

### B. E.S.D. and Latch-Up Testing

The RU84-0 die type has been found to have all pins able to withstand an HBM transient pulse of +/-2500V per JEDEC JESD22-A114. Latch-Up testing has shown that this device withstands a current of +/-250mA and overvoltage per JEDEC JESD78.

**Table 1**  
Reliability Evaluation Test Results

**MAX14946EWE+T**

TEST ITEM	TEST CONDITION	FAILURE IDENTIFICATION	SAMPLE SIZE	NUMBER OF FAILURES	COMMENTS
<b>Static Life Test</b> (Note 1)	Ta = 135C Biased Time = 192 hrs.	DC Parameters & functionality	80	0	

Note 1: Life Test Data may represent plastic DIP qualification lots.